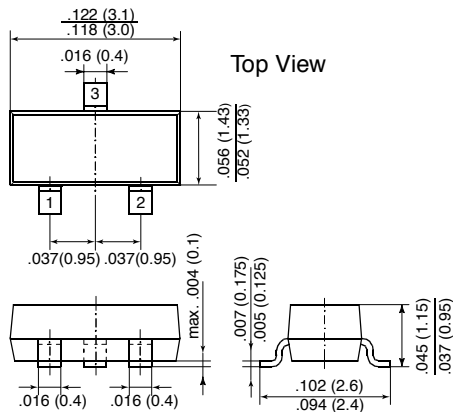


MMBT3904

Small Signal Transistors (NPN)

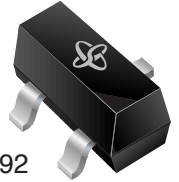
SOT-23



Dimensions in inches and (millimeters)
Pin configuration
1 = Base, 2 = Emitter, 3 = Collector.

FEATURES

- ◆ NPN Silicon Epitaxial Planar Transistor for switching and amplifier applications.
- ◆ As complementary type, the PNP transistor MMBT3906 is recommended.
- ◆ This transistor is also available in the TO-92 case with the type designation 2N3904.



MECHANICAL DATA

Case: SOT-23 Plastic Package

Weight: approx. 0.008g

Marking code: 1AM

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified

	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Collector Current	I_C	200	mA
Power Dissipation at $T_A = 25^\circ\text{C}$	P_{tot}	225 ⁽¹⁾ 300 ⁽²⁾	mW
Thermal Resistance Junction to Substrate Backside	$R_{\theta SB}$	320 ⁽¹⁾	°C/W
Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	450 ⁽¹⁾	°C/W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_S	-65 to +150	°C

NOTES:

(1) Device on fiberglass substrate, see layout.

(2) Device on alumina substrate.

MMBT3904

ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified

	SYMBOL	MIN.	MAX.	UNIT
Collector-Base Breakdown Voltage at $I_C = 10\ \mu\text{A}$, $I_E = 0$	$V_{(BR)CBO}$	60	—	V
Collector-Emitter Breakdown Voltage at $I_C = 1\ \text{mA}$, $I_B = 0$	$V_{(BR)CEO}$	40	—	V
Emitter-Base Breakdown Voltage at $I_E = 10\ \mu\text{A}$, $I_C = 0$	$V_{(BR)EBO}$	6.0	—	V
Collector Saturation Voltage at $I_C = 10\ \text{mA}$, $I_B = 1\ \text{mA}$ at $I_C = 50\ \text{mA}$, $I_B = 5\ \text{mA}$	V_{CEsat} V_{CEsat}	— —	0.2 0.3	V V
Base Saturation Voltage at $I_C = 10\ \text{mA}$, $I_B = 1\ \text{mA}$ at $I_C = 50\ \text{mA}$, $I_B = 5\ \text{mA}$	V_{BEsat} V_{BEsat}	— —	0.85 0.95	V V
Collector-Emitter Cutoff Current $V_{EB} = 3\ \text{V}$, $V_{CE} = 30\ \text{V}$	I_{CEV}	—	50	nA
Emitter-Base Cutoff Current $V_{EB} = 3\ \text{V}$, $V_{CE} = 30\ \text{V}$	I_{EBV}	—	50	nA
DC Current Gain at $V_{CE} = 1\ \text{V}$, $I_C = 0.1\ \text{mA}$ at $V_{CE} = 1\ \text{V}$, $I_C = 1\ \text{mA}$ at $V_{CE} = 1\ \text{V}$, $I_C = 10\ \text{mA}$ at $V_{CE} = 1\ \text{V}$, $I_C = 50\ \text{mA}$ at $V_{CE} = 1\ \text{V}$, $I_C = 100\ \text{mA}$	h_{FE} h_{FE} h_{FE} h_{FE} h_{FE}	40 70 100 60 30	— — 300 — —	— — — — —
Input Impedance at $V_{CE} = 10\ \text{V}$, $I_C = 1\ \text{mA}$, $f = 1\ \text{kHz}$	h_{ie}	1	10	k Ω
Gain-Bandwidth Product at $V_{CE} = 20\ \text{V}$, $I_C = 10\ \text{mA}$, $f = 100\ \text{MHz}$	f_T	300	—	MHz
Collector-Base Capacitance at $V_{CB} = 5\ \text{V}$, $f = 100\ \text{kHz}$	C_{CBO}	—	4	pF
Emitter-Base Capacitance at $V_{EB} = 0.5\ \text{V}$, $f = 100\ \text{kHz}$	C_{EBO}	—	8	pF

MMBT3904

ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified

	SYMBOL	MIN.	MAX.	UNIT
Voltage Feedback Ratio $V_{CE} = 10 \text{ V}$, $I_C = 1 \text{ mA}$, $f = 1 \text{ kHz}$	h_{re}	$0.5 \cdot 10^{-4}$	$8 \cdot 10^{-4}$	—
Small Signal Current Gain at $V_{CE} = 10 \text{ V}$, $I_C = 1 \text{ mA}$, $f = 1 \text{ kHz}$	h_{fe}	100	400	—
Output Admittance at $V_{CE} = 1 \text{ V}$, $I_C = 1 \text{ mA}$, $f = 1 \text{ kHz}$	h_{oe}	1	40	μS
Noise Figure at $V_{CE} = 5 \text{ V}$, $I_C = 100 \mu\text{A}$, $R_G = 1 \text{ k}\Omega$, $f = 10 \dots 15000 \text{ Hz}$	NF	—	5	dB
Delay Time (see Fig. 1) at $I_{B1} = 1 \text{ mA}$, $I_C = 10 \text{ mA}$	t_d	—	35	ns
Rise Time (see Fig. 1) at $I_{B1} = 1 \text{ mA}$, $I_C = 10 \text{ mA}$	t_r	—	35	ns
Storage Time (see Fig. 2) at $-I_{B1} = I_{B2} = 1 \text{ mA}$, $I_C = 10 \text{ mA}$	t_s	—	200	ns
Fall Time (see Fig. 2) at $-I_{B1} = I_{B2} = 1 \text{ mA}$, $I_C = 10 \text{ mA}$	t_f	—	50	ns

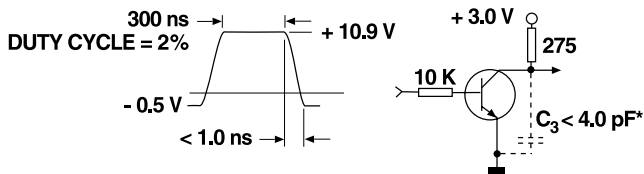


Fig. 1: Test circuit for delay and rise time

* total shunt capacitance of test jig and connectors

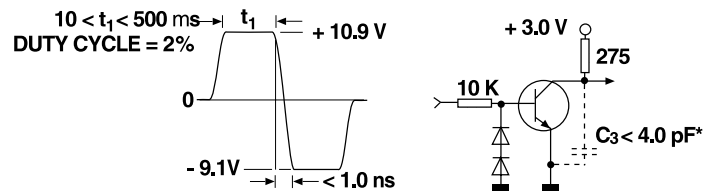
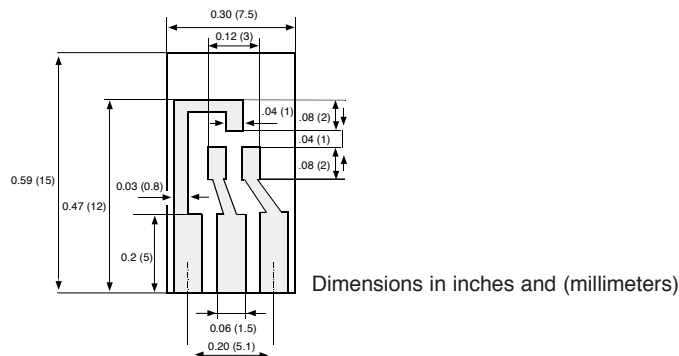


Fig. 2: Test circuit for storage and fall time

* total shunt capacitance of test jig and connectors



Layout for R_{thJA} test

Thickness: Fiberglass 0.059 in (1.5 mm)

Copper leads 0.012 in (0.3 mm)